# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





LTC5508

300MHz to 7GHz RF Power Detector with Buffered Output in SC70 Package

#### FEATURES

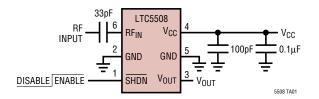
- Temperature Compensated Internal Schottky Diode RF Detector
- Wide Input Frequency Range: 300MHz to 7GHz
- Wide Input Power Range: -32dBm to 12dBm
- Buffered Detector Output
- Wide V<sub>CC</sub> Range of 2.7V to 6V
- Low Operating Current: 550µA
- Low Shutdown Current: <2µA</p>
- SC70 Package

# **APPLICATIONS**

- **8**02.11a, 802.11b, 802.11g, 802.15
- Multimode Mobile Phone Products
- Optical Data Links
- Wireless Data Modems
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

# TYPICAL APPLICATION

#### 300MHz to 7GHz RF Power Detector



#### DESCRIPTION

The LTC<sup>®</sup>5508 is an RF power detector for RF applications operating in the 300MHz to 7GHz range. A temperature compensated Schottky diode peak detector and buffer amplifier are combined in a small SC70 package. The supply voltage range is optimized for operation from a single lithium-ion cell or 3xNiMH.

The RF input voltage is peak detected using an on-chip Schottky diode. The detected voltage is buffered and supplied to the  $V_{OUT}$  pin. A power saving shutdown mode reduces supply current to less than  $2\mu$ A.

The LTC5508 operates with input power levels from -32 dBm to 12 dBm.

C, LTC and LT are registered trademarks of Linear Technology Corporation.

# $10000 \\ \hline V_{CC} = 3.6V \\ \hline T_A = 25^{\circ}C \\ \hline 0000 \\ \hline$

#### **Output Voltage vs RF Input Power**

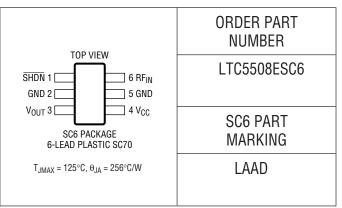


# **ABSOLUTE MAXIMUM RATINGS**

(Note 1)

$V_{CC}$ , $V_{OUT}$ to GND0.3V to 6.5V
$RF_{IN}$ Voltage (V <sub>CC</sub> ± 1.3V) to 7V
SHDN Voltage to GND $-0.3V$ to (V <sub>CC</sub> + 0.3V)
I <sub>VOUT</sub>
Operating Temperature Range (Note 2) – 40°C to 85°C
Maximum Junction Temperature 125°C
Storage Temperature Range – 65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

#### PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

**ELECTRICAL CHARACTERISTICS** The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T<sub>A</sub> = 25°C. V<sub>CC</sub> = 3.6V, SHDN = V<sub>CC</sub> = HI, SHDN = 0V = LO, RF Input Signal is Off, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
V <sub>CC</sub> Operating Voltage		2.7		6	V
I <sub>VCC</sub> Shutdown Current	SHDN = LO			2	μA
I <sub>VCC</sub> Operating Current	$\overline{\text{SHDN}}$ = HI, I <sub>VOUT</sub> = 0mA		0.55	0.85	mA
V <sub>OUT</sub> V <sub>OL</sub> (No RF Input)	$R_{LOAD} = 2k$ , $\overline{SHDN} = HI$ , Enabled SHDN = LOW, Disabled	150	250 1	400	mV mV
V <sub>OUT</sub> Output Current	$V_{OUT} = 1.75V, V_{CC} = 2.7V, \Delta V_{OUT} = 10mV$	1	2		mA
V <sub>OUT</sub> Enable Time	$\overline{\text{SHDN}}$ = HI, C <sub>LOAD</sub> = 33pF, R <sub>LOAD</sub> = 2k		8	20	μs
V <sub>OUT</sub> Bandwidth	$C_{LOAD} = 33pF, R_{LOAD} = 2k$ (Note 4)		2		MHz
V <sub>OUT</sub> Load Capacitance	(Note 6)			33	pF
V <sub>OUT</sub> Slew Rate	$V_{RFIN} = 2V$ Step, $C_{LOAD} = 33$ pF, $R_{LOAD} = 2k$ (Note 3)		5		V/µs
V <sub>OUT</sub> Noise	$V_{CC}$ = 3V, Noise BW = 1.5MHz, 50 $\Omega$ RF Input Termination		2		mV <sub>P-P</sub>
SHDN Voltage, Chip Disabled	V <sub>CC</sub> = 2.7V to 6V			0.35	V
SHDN Voltage, Chip Enabled	V <sub>CC</sub> = 2.7V to 6V	1.4			V
SHDN Input Current	SHDN = 3.6V		24	40	μA
RF <sub>IN</sub> Input Frequency Range			300 to 7000		MHz
RF <sub>IN</sub> Input Power Range	RF Frequency = 300MHz to 7GHz (Note 5, 6) $V_{CC}$ = 2.7V to 6V		-32 to 12		dBm
RF <sub>IN</sub> AC Input Resistance	F = 1000MHz, Pin = -25dBm		150		Ω
RF <sub>IN</sub> Input Shunt Capacitance	F = 1000MHz, Pin = -25dBm		0.6		pF

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: The rise time at V<sub>OUT</sub> is measured between 0.5V and 1.5V.

**Note 4:** Bandwidth is calculated using the 10% to 90% rise time equation: BW = 0.35/rise time.

Note 5: RF performance is tested at 1800MHz

Note 6: Guaranteed by design.



#### **TYPICAL PERFORMANCE CHARACTERISTICS**

40

RF INPUT POWER (dBm)

, -32-28-24-20-16-12-8-40

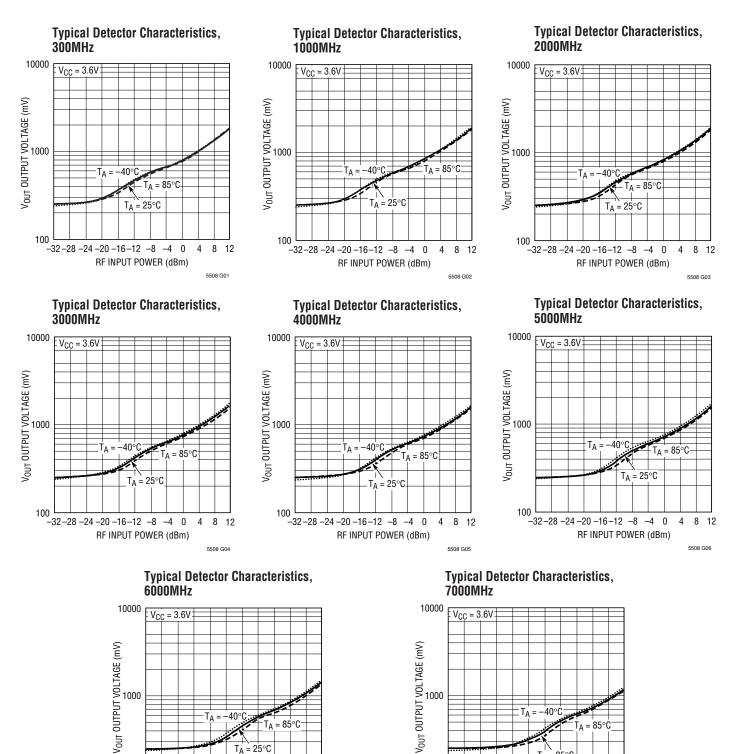
85ं°C

4 8 12

5508 G07

ΤA

T<sub>A</sub> = 25°C



100

5508fa

TΑ . 40°

-32-28-24-20-16-12-8-4

100

85°

5508 G08

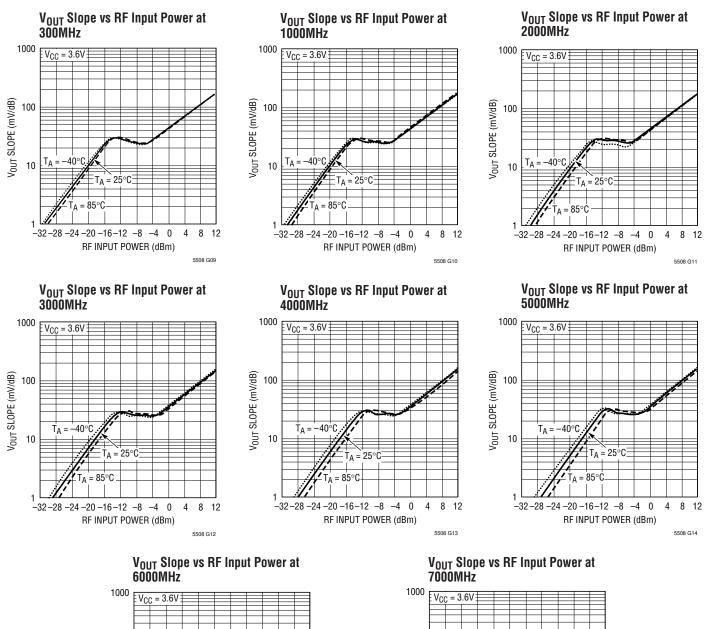
Δ =

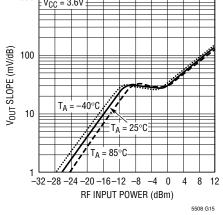
0 4 8 12

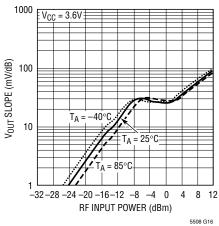
T<sub>A</sub> = 25°C

RF INPUT POWER (dBm)

# **TYPICAL PERFORMANCE CHARACTERISTICS**



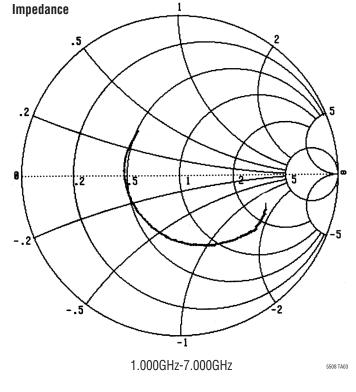






# TYPICAL PERFORMANCE CHARACTERISTICS

Input Impedance (Pin = 0dBm, $V_{CC}$ = 3.6V, $T_A$ = 25°C)		
FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	129.136	-86.960
1.375	100.771	-92.142
1.750	73.844	-81.141
2.125	60.159	-68.796
2.500	50.135	-58.139
2.875	43.042	-48.927
3.250	37.570	-41.033
3.625	33.924	-33.346
4.000	30.923	-26.405
4.375	28.793	-20.012
4.750	26.992	-14.080
5.125	25.717	-8.323
5.500	24.920	-3.228
5.875	24.318	2.177
6.250	24.549	7.535
6.625	25.273	12.197
7.000	26.337	16.503

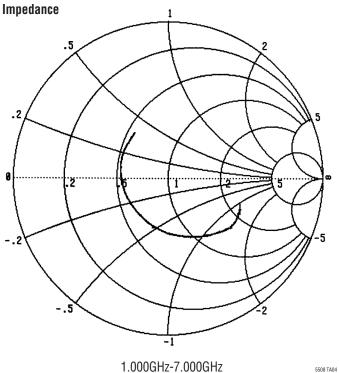


#### $RF_{IN}$ Input Impedance (Pin = -25dBm, $V_{CC}$ = 3.6V, $T_A$ = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	114.531	-63.267
1.375	95.061	-71.669
1.750	71.491	-64.607
2.125	59.563	-54.798
2.500	51.714	-46.844
2.875	44.940	-39.753
3.250	39.708	-32.738
3.625	36.151	-26.385
4.000	33.227	-20.478
4.375	31.108	-15.107
4.750	29.514	-9.941
5.125	27.899	-4.793
5.500	27.047	0.266
5.875	26.627	5.250
6.250	26.760	10.267
6.625	27.619	14.616
7.000	28.241	18.523



**S11** Forward Reflection



J IMU4



# **PIN FUNCTIONS**

**SHDN** (Pin 1): Shutdown Input. A logic low on the SHDN pin places the part in shutdown mode. A logic high enables the part. SHDN has an internal 150k pull down resistor to ensure that the part is in shutdown when no input is applied.

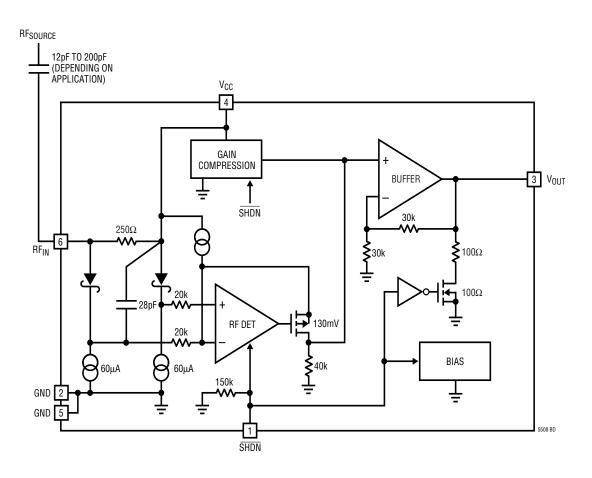
GND (Pin 2, 5): Ground.

Vout (Pin 3): Detector Output.

**V<sub>CC</sub> (Pin 4):** Power Supply Voltage, 2.7V to 6V. V<sub>CC</sub> should be bypassed appropriately with ceramic capacitors.

 $\mathbf{RF_{IN}}$  (Pin 6): RF Input Voltage. Referenced to V<sub>CC</sub>. A coupling capacitor must be used to connect to the RF signal source. The frequency range is 300MHz to 7GHz. This pin has an internal 250 $\Omega$  termination, an internal Schottky diode detector and a peak detector capacitor.

# **BLOCK DIAGRAM**





#### APPLICATIONS INFORMATION

#### Operation

The LTC5508 RF detector integrates several functions to provide RF power detection over frequencies ranging from 300MHz to 7GHz. These functions include an internally compensated buffer amplifier, an RF Schottky diode peak detector and level shift amplifier to convert the RF input signal to DC, a delay circuit to avoid voltage transients at  $V_{OUT}$  when coming out of shutdown and a gain compression circuit to extend the detector dynamic range.

#### **Buffer Amplifier**

The buffer amplifier has a gain of two and is capable of driving a 2mA load. The buffer amplifier typically has an output voltage range of 0.25V to 1.75V.

#### **RF** Detector

The internal RF Schottky diode peak detector and level shift amplifier converts the RF input signal to a low frequency signal. The detector demonstrates excellent efficiency and linearity over a wide range of input power. The Schottky detector is biased at about  $60\mu$ A and drives a peak detector capacitor of 28pF.

#### **Gain Compression**

The gain compression circuit changes the feedback ratio as the RF peak-detected input voltage increases above 60mV. Below 60mV, the voltage gain from the peak detector to the buffer output is 4. Above 120mV, the voltage gain is reduced to 0.85. The compression expands the low power detector range due to higher gain.

#### **Modes of Operation**

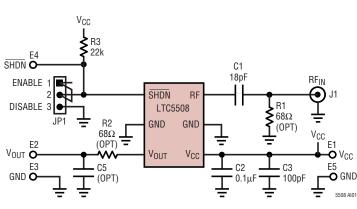
MODE	SHDN OPERATION	
Shutdown	Low	Disabled
Enable	High	Power Detect

#### **Applications**

The LTC5508 can be used as a self-standing signal strength measuring receiver for a wide range of input signals from -32dBm to 12dBm for frequencies from 300MHz to 7GHz.

The LTC5508 can be used as a demodulator for AM and ASK modulated signals with data rates up to 2MHz. Depending on specific application needs, the RSSI output can be split into two branches, providing AC-coupled data (or audio) output and DC-coupled, RSSI output for signal strength measurements and AGC.

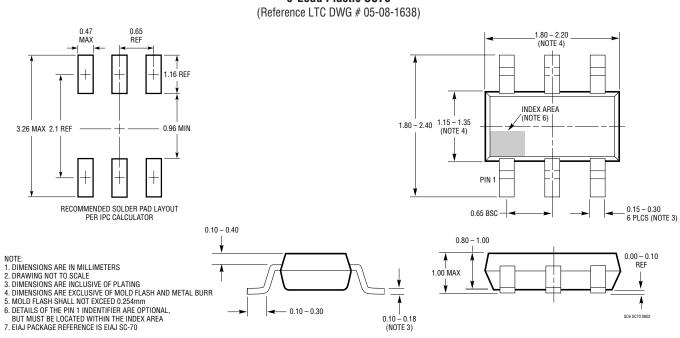
The LTC5508 can be used for RF power detection and control. Refer to Application Note 91, "Low Cost Coupling Methods for RF Power Detectors Replace Directional Couplers."







# PACKAGE DESCRIPTION



SC6 Package 6-Lead Plastic SC70 (Reference LTC DWG # 05-08-1638)

# **RELATED PARTS**

PART NUMBER	DESCRIPTION COMMENTS			
RF Power Controllers				
LTC1757A	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones		
LTC1758	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones		
LTC1957	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones		
LTC4400	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW		
LTC4401	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW		
LT5500	1.8GHz to 2.7GHz RF Front End	Dual LNA gain Setting +13.5dB/–14dB at 2.5GHz, Double-Balanced Mixer, $1.8V \leq V_{SUPPLY} \leq 5.25V$		
LT5502	400MHz Quadrature Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range		
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth		
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply		
LTC5505	300MHz to 3.5GHz RF Power Detector	>40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply		
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, –4dB to 57dB Linear Power Gain		
LTC5507	100kHz to 1GHz RF Power Detector	48dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply		
LT5511	High Signal Level Up Converting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer		
LT5512	High Signal Level Down Converting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer		



5508fa LT/TP REV A 0603 1K • PRINTED IN USA LINEAR TECHNOLOGY CORPORATION 2002